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VS-SD400N/R Series

Vishay Semiconductors

Standard Recovery Diodes, (Stud Version), 400 A



PRIMARY CHARACTERISTICS				
I _{F(AV)}	400 A			
Package	DO-9 (DO-205AB)			
Circuit configuration	Single			

FEATURES

- Wide current range
- High voltage ratings up to 2400 V
- · High surge current capabilities
- Stud cathode and stud anode version
- Standard JEDEC[®] types
- Compression bonded encapsulations
- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

- Converters
- Power supplies
- Machine tool controls
- High power drives
- Medium traction applications

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST CONDITIONS	VALUES	UNITS	
		480	A	
I _{F(AV)}	T _C	120	O°	
I _{F(RMS)}		630		
IFSM	50 Hz	8250	А	
	60 Hz	8640		
l ² t	50 Hz	340	kA ² s	
	60 Hz	311	KA-S	
V _{RRM}	Range	1600 to 2400	V	
TJ		-40 to +190	C°	

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS						
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} MAXIMUM AT T _J = T _J MAXIMUM mA		
	16	1600	1700			
VS-SD400N/R	20	2000	2100	15		
	24	2400	2500			

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FORWARD CONDUCTION						
PARAMETER	SYMBOL	L TEST CONDITIONS		VALUES	UNITS	
		180° conduction, half sine wave		400	A	
Maximum average forward current	I _{F(AV)}			120	°C	
at case temperature				480	A	
					100	°C
Maximum RMS forward current	I _{F(RMS)}	DC at 110	°C case tempe	rature	630	
		t = 10 ms	No voltage	Sinusoidal half wave,	8250	
Maximum peak, one-cycle forward,		t = 8.3 ms	reapplied		8640	A
non-repetitive surge current	IFSM	t = 10 ms	100 % V _{RRM}		6940	
		t = 8.3 ms	reapplied		7270	
	l ² t	t = 10 ms	No voltage	initial $T_J = T_J maximum$	340	kA ² s
Maximum I ² t for fusing		t = 8.3 ms	reapplied		311	
Maximum 14t for fusing		t = 10 ms	100 % V _{RRM} reapplied		241	
		t = 8.3 ms			220	
Maximum I ² \sqrt{t} for fusing	l²√t	t = 0.1 to 10 ms, no voltage reapplied		3400	kA²√s	
Low level value of threshold voltage	V _{F(TO)1}	(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum		0.80	v	
High level value of threshold voltage	V _{F(TO)2}	$(I > \pi x I_{F(AV)}), T_J = T_J maximum$		0.85		
Low level value of forward slope resistance	r _{f1}	(16.7 % x π x $I_{F(AV)} < I < \pi$ x $I_{F(AV)}$), T _J = T _J maximum		0.55	mW	
High level value of forward slope resistance	r _{f2}	$(I > \pi x I_{F(AV)}), T_J = T_J maximum$		0.51	11177	
Maximum forward voltage drop	V _{FM}	$I_{pk} = 1500 \text{ A}, T_J = T_J \text{ maximum,}$ $t_p = 10 \text{ ms sinusoidal wave}$		1.62	V	

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction operating temperature range	TJ		-40 to +190	°C	
Maximum storage temperature range	T _{Stg}		-55 to +200		
Maximum thermal resistance, junction to case	R _{thJC} DC operation		0.11	K/W	
Maximum thermal resistance, case to heatsink	R _{thCS}	nCS Mounting surface, smooth, flat and greased		rv/ VV	
Maximum allowed mounting torque ± 10 %		Not-lubricated threads	27	Nm	
Approximate weight			250	g	
Case style		See dimensions (link at the end of datasheet DO-9 (DO-7		-205AB)	

$\Delta \mathbf{R}_{\text{thJC}}$ CONDUCTION				
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS
180°	0.020	0.013		
120°	0.023	0.023		
90°	0.029	0.031	$T_J = T_J maximum$	K/W
60°	0.042	0.044		
30°	0.073	0.074		

Note

• The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

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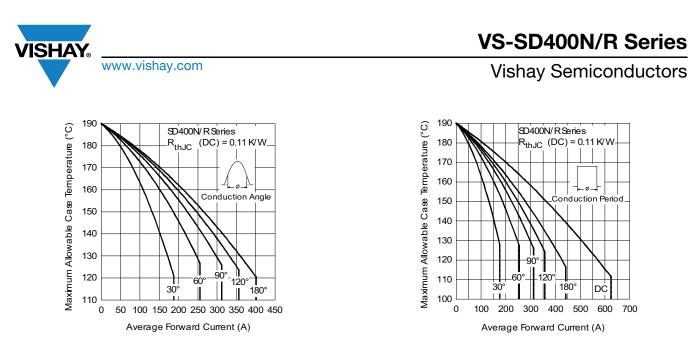
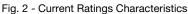


Fig. 1 - Current Ratings Characteristics



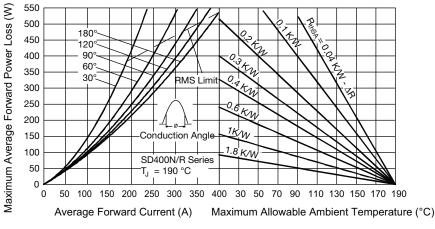
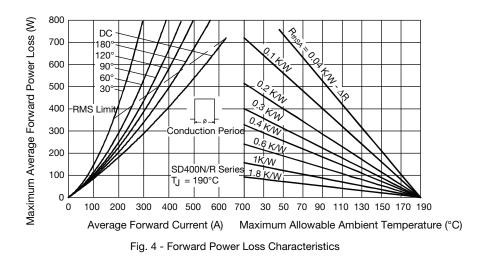
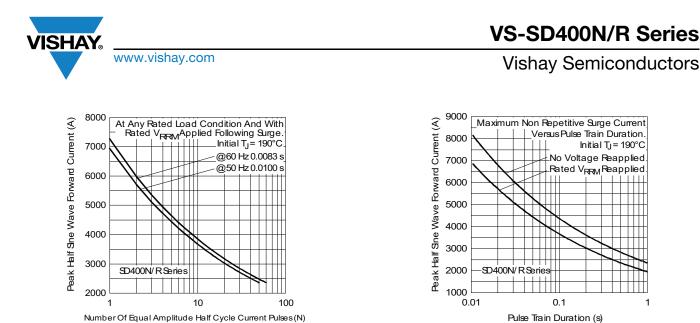


Fig. 3 - Forward Power Loss Characteristics





Number Of Equal Amplitude Half Cycle Current Pulses(N)

Fig. 5 - Maximum Non-Repetitive Surge Current



1

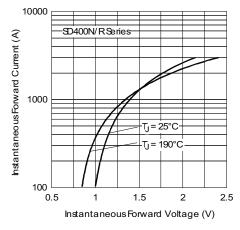


Fig. 7 - Forward Voltage Drop Characteristics

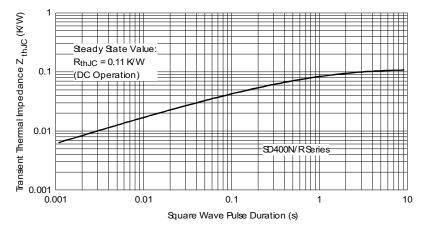


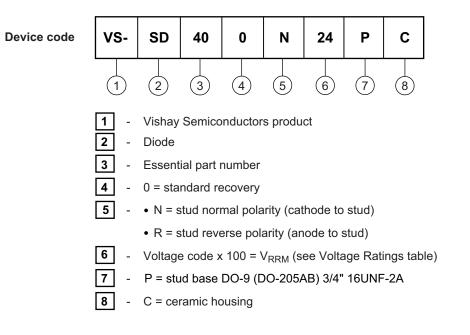
Fig. 8 - Thermal Impedance ZthJC Characteristic



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ORDERING INFORMATION TABLE



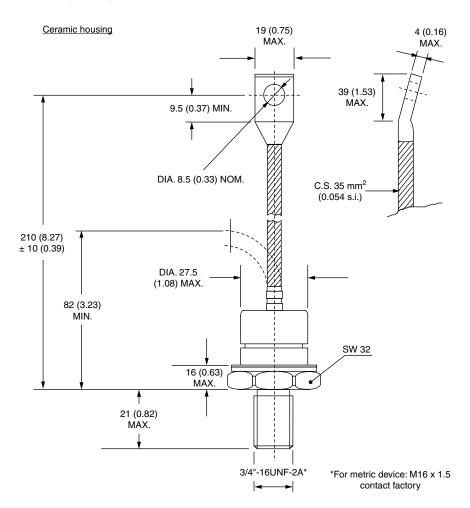
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95301			

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DO-205AB (DO-9)

DIMENSIONS in millimeters (inches)





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